

|   | Type | L # | Hits      | Search Text  | DBs   |
|---|------|-----|-----------|--|---|
| 1 | BRS  | L1  | 1378<br>0 | trench near5<br>(isolation or "field<br>oxide" or LOCOS)   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB |
| 2 | BRS  | L2  | 1402<br>2 | trench near5 (liner<br>or line or<br>conductive or metal<br>or "tungsten<br>silicide" or<br>"titanium nitride"<br>or "silicon nitride"<br>or tungsten or<br>polysilicon) | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB |
| 3 | BRS  | L3  | 4579      | 1 and 2  | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB |
| 4 | BRS  | L4  | 4220      | semiconductor and 3  | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB |
| 5 | BRS  | L5  | 3994      | @ad<=20011012 and 4  | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB |
| 6 | BRS  | L7  | 2029      | 257/\$ and 5   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB |
| 7 | BRS  | L9  | 1965      | 5 not 7  | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB |